

isc Silicon PNP Power Transistor

ZXT953K

DESCRIPTION

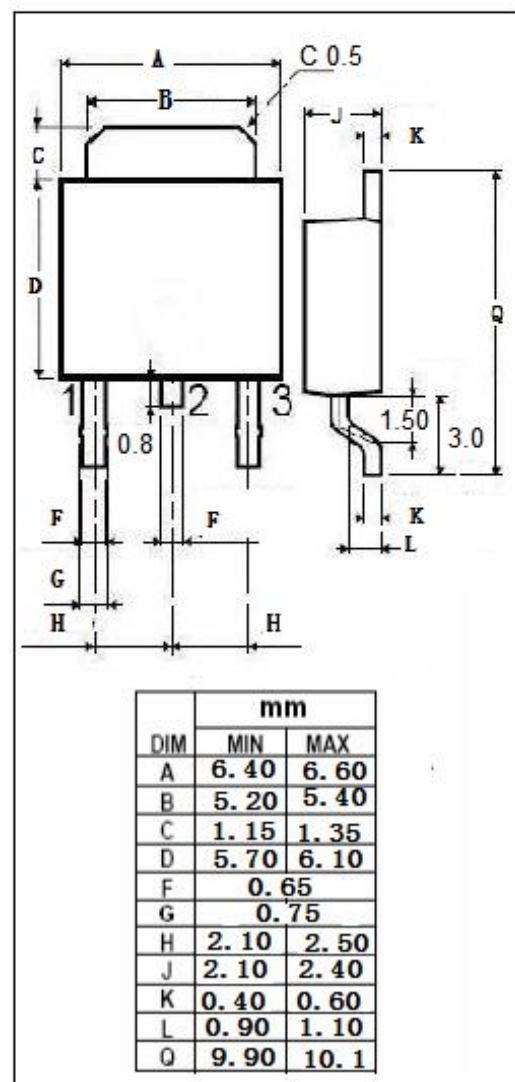
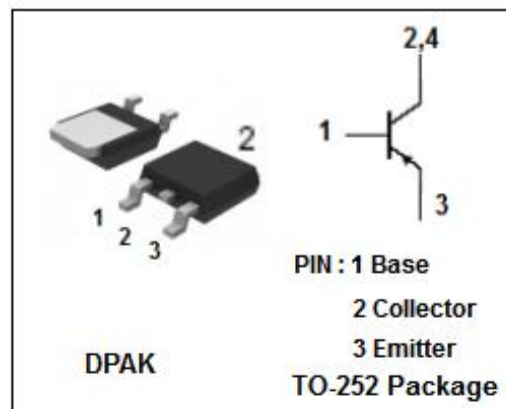
- With TO-252(DPAK) packaging
- Excellent linearity of h_{FE}
- Low collector-to-emitter saturation voltage
- Fast switching speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Relay drivers, high-speed inverters , converters
- Other general high current switching applications

ABSOLUTE MAXIMUM RATINGS($T_a=25^{\circ}\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	-140	V
V_{CEO}	Collector-Emitter Voltage	-100	V
V_{EBO}	Emitter-Base Voltage	-7	V
I_C	Collector Current-Continuous	-5	A
I_{CP}	Collector Current-Continuous	-10	A
I_B	Base Current	-0.5	A
P_C	Collector Power Dissipation	4.2	W
T_J	Junction Temperature	150	$^{\circ}\text{C}$
T_{stg}	Storage Temperature Range	-55~150	$^{\circ}\text{C}$



isc Silicon PNP Power Transistor

ZXT953K

ELECTRICAL CHARACTERISTICS

 $T_c=25^{\circ}\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV_{CBO}	Collector-Base Breakdown Voltage	$I_C=-0.1\text{mA}; I_B=0$	-140			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C=-10\text{mA}; I_B=0$	-100			V
$V_{CE(sat)-1}$	Collector-Emitter Saturation Voltage	$I_C=-0.1\text{A}; I_B=-10\text{mA}$			-0.30	mV
$V_{CE(sat)-2}$	Collector-Emitter Saturation Voltage	$I_C=-1.0\text{A}; I_B=-100\text{mA}$			-0.100	mV
$V_{CE(sat)-3}$	Collector-Emitter Saturation Voltage	$I_C=-2.0\text{A}; I_B=-200\text{mA}$			-0.175	mV
$V_{CE(sat)-4}$	Collector-Emitter Saturation Voltage	$I_C=-5.0\text{A}; I_B=-500\text{mA}$			-0.390	mV
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C=-5.0\text{A}; I_B=-500\text{mA}$			-1.10	V
I_{CBO}	Collector Cutoff Current	$V_{CB}=-140\text{V}; I_E=0$			-20	μA
I_{EBO}	Emitter Cutoff Current	$V_{EB}=-7\text{V}; I_C=0$			-10	μA
h_{FE-1}	DC Current Gain	$I_C=-0.01\text{A}; V_{CE}=-1\text{V}$	100			
h_{FE-2}	DC Current Gain	$I_C=-1\text{A}; V_{CE}=-1\text{V}$	100		300	
h_{FE-3}	DC Current Gain	$I_C=-3\text{A}; V_{CE}=-1\text{V}$	50			
h_{FE-4}	DC Current Gain	$I_C=-5\text{A}; V_{CE}=-1\text{V}$	15			
h_{FE-5}	DC Current Gain	$I_C=-10\text{A}; V_{CE}=-1\text{V}$				

Notice:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.

